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"Cold spots": a new model for transport in high T_c cuprates

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We present a Boltzmann equation analysis of the transport properties of a model of electrons with a lifetime which is short everywhere except near the Brillouin zone diagonals. The anomalous lifetime is directly implied by photoemission and c-axis transport data. We find quantitative agreement between calculations and ac and dc longitudinal and Hall resistivity, but the predicted longitudinal magnetoresistance disagrees with experiment. A possible microscopic origin of the anomalous lifetime is discussed.

I. INTRODUCTION

Normal state transport in high-T_c superconductors remains a controversial subject. There are two broad classes of theoretical approaches: the (generalized) fermi liquid, in which the basic current carrying entities are electrons, and the non fermi liquid in which the basic entities are more exotic objects, e.g. spinons and holons [1], phase fluctuations of a superconducting order parameter [2,3] or fermions with definite charge conjugation symmetry [4]. In fermi-liquid based approaches one must invoke an anomalous scattering mechanism. Various models have been proposed [5–7]; a central concept is the "hot spot", a small region on the fermi surface (typically taken to be near the $(\pi, 0)$ and $(0, \pi)$ points) where the electron lifetime is unusually short and has an anomalous temperature dependence. Hot spots arise e.g. in models involving antiferromagnetic fluctuations strongly peaked at a particular momentum transfer. Models involving hot spots have had some successes, but have not led to complete and generally accepted descriptions of cuprate physics [7,8].

In this paper we argue that the data are better described in terms of *cold spots*: small regions which we take to be near the zone diagonal and in which we assume the lifetime is much *longer* than elsewhere on the Fermi surface A somewhat similar model was recently put forward by Zheleznyak et. al. [9] and the idea bears an intriguing resemblance to the 'fermi segments' appearing in a phenomenological model of preformed pairs [10] and found in recent $SU(2)$ gauge theory calculations [11]

We do not at present have a controlled calculation from a microscopic model which produces cold spots; we suggest however that they might arise from strong $d_{x^2-y^2}$ pairing fluctuations of the type proposed in [10], and we present a leading order estimate along these lines in section IV below. There are four phenomenological justifications. One is the apparently successful description of transport and most aspects of magnetotransport to be discussed at length below. A second justification comes from photoemission. Experiments [12,13] on optimally doped curprates show that for momenta parallel to (π, π) the electron spectral function exhibits a reasonably well-defined quasiparticle peak, suggesting relatively weak scattering. However, for momenta near $(\pi, 0)$ or $(0, \pi)$, there is no discernible peak (at $T > T_c$): the spectral function is very broad, suggesting relatively strong scattering. Thus photoemission implies a lifetime which is generically short but has a pronounced angular dependence. A third justification comes from c-axis transport. In optimally doped materials the observed ρ_c is large, and only weakly temperature dependent, while ρ_{ab} is small, and strongly temperature dependent. The anisotropy ρ_c/ρ_{ab} increases strongly as T is decreased. Within a fermi liquid picture this is explicable only if the two quantities are controlled by different parts of the fermi surface. Band theory calculations have shown that this may occur in high T_c materials: the calculated between-planes hopping $t_\perp(\vec{p})$ is strongly momentum dependent, vanishing for momenta parallel to (π, π) and being maximal for momenta parallel to $(\pi, 0)$ [14,15]. Therefore the observation of very different temperature dependences of ρ_{ab} and ρ_c implies that ρ_{ab} must be controlled by carriers with momentum nearly parallel to (π, π) and that these carriers must have a much longer lifetime than do carriers on other parts of the Fermi surface. A fourth argument concerns the anomalously small vortex viscosity measured by Parks *et al* [16] or inferred from resistivity data [17]. This, it has been argued, can only be explained by a strongly anisotropic scattering rate.

The remainder of this paper is organized as follows. In section II we present the model and derive an approximate solution. In section III we compare the solution to data and present new experimental tests. In section IV we discuss a possible microscopic origin. Section V is a conclusion.

II. MODEL

To motivate the model, we consider the c-axis conductivity σ_c. In very anisotropic systems such as high-Tc superconductors an adequate theoretical expression is

$$\sigma_c(T) = \int \frac{d^2p}{(2\pi)^2} t_\perp(p)^2 G_R(p,\omega) G_A(p,\omega) \frac{\partial f}{\partial \omega} \qquad (1)$$

Here $t_\perp(p)$ is the interplane hopping, $f(\omega)$ is the fermi function and $G_{R,A}$ are the retarded and advanced in-plane Green functions evaluated at the chemical potential, which in our conventions is $\omega = 0$. Band structure calculations yield

$$t_\perp(p) = \frac{t_0}{4}[\cos(p_x) - \cos(p_y)]^2$$

with $t_0 \approx 0.15\ eV$ for bilayer $BSCCO$. In a fermi liquid,

$$G_{R,A}(p,\omega) = Z/(\omega - \epsilon_p \pm i\Gamma_p) + G_{inc} \qquad (2)$$

Here $1 > Z > 0$ is the quasiparticle renormalization factor, ϵ_p is the (renormalized) fermi velocity and Γ_p is a scattering rate. In a conventional fermi liquid at low T, $\Gamma_p = (2\tau_{imp})^{-1} + \omega^2 + T^2$ with τ_{imp} an impurity scattering time. Evaluating Eq. 1 using Eq. 2 and neglecting the incoherent part yields

$$\sigma_c(T) = \int (dp) t_\perp(p)^2 N(p) Z^2(p)/2\Gamma_p \qquad (3)$$

Here (dp) denotes an integral along the fermi line. The main temperature dependence in this formula comes from Γ, so in a conventional fermi liquid in which quantities depend only weakly on position on the fermi surface, $\rho_c \sim \Gamma(T)$ would have the same temperature dependence as $\rho_{ab} = m\Gamma(T)/(ne^2)$. To explain the observed T-dependence of ρ_c/ρ_{ab} one must either assume $Z \to 0$ (i.e. non fermi liquid behavior) or invoke a strong angular dependence in Γ. In this paper we study the consequences of the latter assumption. Because ρ_c is large and has only a weak T-dependence in optimally doped materials, over most of the Fermi surface Γ must be large and have only a weak temperature dependence. Because ρ_{ab} is small and temperature dependent Γ must be small and temperature dependent in the parts of the Fermi surface where $t_\perp(p)$ vanishes. Therefore we assume that Γ has a large, angular dependent part which vanishes quadratically for momenta parallel to (π,π) and has negligible frequency and temperature dependence. We parametrize the fermi surface by a magnitude $p_F(\theta)$ and angle θ, with $\theta = 0$ corresponding to $\vec{p}$ along the zone diagonal and write

$$\Gamma(\theta,T) = \frac{1}{4}\Gamma_0 \sin^2(2\theta) + \frac{1}{\tau_{FL}} \qquad (4)$$

Near the diagonals we approximate

$$\Gamma(\theta,T) = \Gamma_0\theta^2 + \frac{1}{\tau_{FL}} \qquad (5)$$

The fermi-liquid scattering rate, $1/\tau_{FL}$, is taken to be the sum of an impurity part and a T^2 part; explicitly

$$\frac{1}{\tau_{FL}} = \frac{1}{\tau_{imp}} + \frac{T^2}{T_0} \qquad (6)$$

Here T_0 is an energy scale which in conventional Fermi liquid is of the order of the Fermi temperature but which we take as an adjustable parameter; we will find that it is small of the order of 15 meV for optimally doped $YBaCuO$, suggesting that even the diagonal scattering is stronger than in a usual Fermi liquid. Note that τ_{FL} may in pronciple have ω dependence as well but we assume that it is weak because fluctuations causing the scattering are slow.

The parameter Γ_0 may be estimated from photoemission experiments. In optimally doped cuprates in the normal state one observes near the $(0,\pi)$ point a very broad weakly dispersing feature with an energy half-width $> 0.1eV$ (see e.g. Fig 6 of Ref [13]), suggesting $\Gamma_0 > 0.4\ eV$. For our numerical estimates we take $\Gamma_0 = 0.6\ eV$ because it fits the optical data well.

To study the effects of this unusual scattering on the electrons we write a relaxation-time Boltzmann equation for the quasiparticle distribution function f_p.

$$[-i\omega + e(\vec{E} + \frac{\vec{v_p}}{c} \times \vec{B}) \cdot \partial_{\vec{p}}] f_p = -\Gamma(f_p - f^0) \qquad (7)$$

Because of the strong variation of Γ we shall be mainly interested in states near the zone diagonal. We therefore introduce coordinates along and perpendicular to the diagonal; only the dependence perpendicular is non-trivial. The Boltzmann equation becomes

$$[-i\omega + \Gamma(\theta,T) + \omega_c(\theta)\partial_\theta]\delta f(\theta,\omega) = -e\vec{E} \cdot \vec{v}(\theta) \frac{\partial f}{\partial \epsilon_p} \qquad (8)$$

This equation may be solved. Because it turns out that the physics is dominated by θ near the zone diagonals we may approximate $\omega_c(\theta)$ and $v(\theta)$ by their values v and ω_c at $\theta = 0$. Then in the first quadrant and for $\vec{E}$ parallel to the zone diagonal we have

$$\delta f(\theta,\omega) = -\frac{eEv}{\omega_c} \frac{\partial f_0}{\partial \epsilon_p} \int_{-\infty}^{\theta} d\theta' \exp[-K(\theta,\theta')] \qquad (9)$$

with

$$K(\theta,\theta') = \frac{1}{\omega_c}[-i\omega + 1/\tau_{FL}](\theta - \theta') + \frac{\Gamma_0}{3\omega_c}(\theta^3 - \theta'^3) \qquad (10)$$

From the solution one may construct currents in the usual way. We have chosen the electric field to be parallel to the zone diagonal so we have

$$j_{\|} = \frac{ep_F}{\pi^2}\int d\theta \delta f(\theta,\omega) \tag{11}$$

$$j_{\perp} = \frac{ep_F}{\pi^2}\int d\theta \theta \delta f(\theta,\omega) \tag{12}$$

At $B=0$, $j_\perp = 0$ and $j_\| = \sigma_{xx}E$ with

$$\sigma_{xx} = \frac{e^2 v_F p_F}{\pi^2}\int d\theta \frac{1}{-i\omega + 1/\tau_{FL} + \Gamma_0\theta^2} = \frac{e^2 v_F p_F}{\pi}\sqrt{\frac{\tau_{FL}}{\Gamma_0}}\frac{1}{\sqrt{1-i\omega\tau_{FL}}} \tag{13}$$

Eq. (13) predicts that if $\tau \sim T^{-2}$ then $\sigma \sim 1/T$, as observed in optimally doped cuprates. Qualitatively this behavior occurs because the conductivity is dominated by a small patch (width T) of weakly scattered (lifetime T^{-2}) electrons. Similarly, the weak field Hall conductivity is

$$\sigma_{xy} = \frac{\sigma_{xx}}{4}\frac{\omega_c\tau_{FL}}{1-i\omega\tau_{FL}} \tag{14}$$

and, expanding to $\mathcal{O}B^2$,

$$\frac{\delta\rho_{xx}}{\rho} = \frac{5}{32}\omega_c^2\tau_{FL}^3\Gamma_0 + \frac{1}{16}(\omega_c\tau_{FL})^2 \tag{15}$$

As we shall see in the next section, all of these formulas agree quantitatively with experiment except for the magnetoresistance. If the leading term in Eq (15) were absent, it would agree also.

These expressions apply in the weak field limit, in which an electron is scattered many times before the magnetic field bends its orbit appreciably. In the present context "appreciably" means that the electron leaves the small patch of size p near the diagonal which dominates conduction, in contrast to the usual case in which "appreciably" means "completes of order one cyclotron orbit." The criterion for the weak field limit $\delta\rho/\rho \ll 1$ is

$$\omega_c \ll \omega_c^* = \frac{(1-i\omega\tau_{FL})^{3/2}}{\tau_{FL}^{3/2}\Gamma_0^{1/2}} \tag{16}$$

In the high field, $\omega_c \gg \omega_c^*$ limit one may calculate by dropping the linear terms in the argument of the exponential. Then calculations give

$$\sigma_{xx} = \frac{2.4e^2 v_F p_F}{\pi^2\sqrt{3}\omega_c}\left(\frac{3\omega_c}{\Gamma_0}\right)^{2/3} \tag{17}$$

and

$$\sigma_{xy} = \frac{e^2 v_F p_F}{\sqrt{3}\pi\Gamma_0} \tag{18}$$

So $\rho_{xy} \sim \omega_c^{2/3}$. This result may be understood as follows: one expects $\rho_{xy} \sim B/n_{eff}$; here the effective number of carriers is the size of the conducting patch which in the high field limit is of order $\theta \sim B^{-1/3}$.

III. APPLICATION TO DATA

We now discuss the applicability of our results to data. We begin with clean, optimally doped $YBa_2Cu_3O_7$. In one sample of this material the resistivity at T_c was about 50 $\mu\Omega cm$ [18]; the mean interplane spacing of 5.5$\AA$ implies $\sigma_{xx} = 10^{-3}\ \Omega^{-1}$ per plane. Photoemission measurements [12] yield a zone-diagonal velocity $v_F = 1.3\ eV\AA$ and $p_F = 0.6\ \AA^{-1}$; use of these values and the observed σ_{xx} per plane implies $\sqrt{\Gamma_0/\tau_{FL}} \approx 60\ meV$. Our rough estimate $\Gamma_0 \approx 0.6\ eV$ then implies $\tau_{FL}^{-1} \approx 6\ meV$ at $T = 100\ K$ and therefore $T_0 \approx 12\ meV$, although the uncertainties are substantial. The observed linearity of the resistivity then implies $\tau_{FL}^{-1} \approx 24\ meV$ at $T = 200\ K$. We next use Eq (13) to fit the observed frequency dependent conductivity. Calculation and data [18] are shown in Fig 1 for $T = 200K$. The best fit corresponds to $1/\tau_{FL} = 21\ meV$, very close to the 24 meV estimated from dc transport. We have also fit 100 K and 300 K data; agreement is comparatively good and leads to a T^2 dependence of $1/\tau_{FL}$.

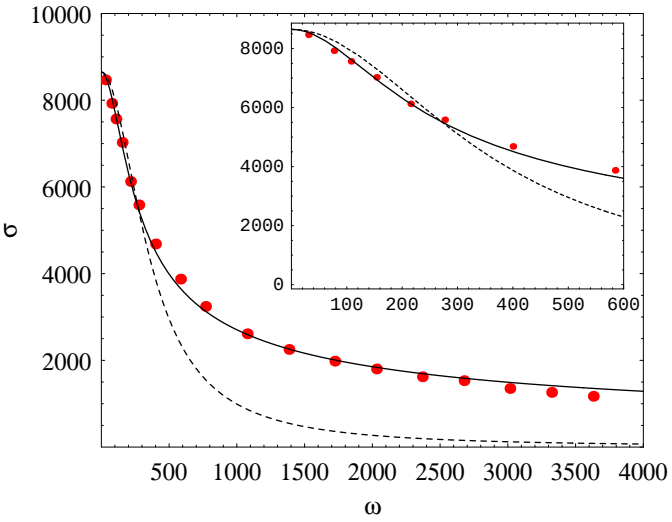

Fig. 1 Optical conductivity, $\sigma(\omega)$, at $T = 200\ K$ in the units of $\Omega^{-1}cm^{-1}$ plotted versus frequency (cm^{-1}): data from Ref [18] (shown as dots) and fit to Eq. (13) with $\tau_{FL}^{-1} = 21\ meV$ shown as solid line. Drude fit with $1/\tau = 2T$ shown as dashed line.

The agreement between model and data is very reasonable; we note especially the narrowness of the Drude peak and the fact that upward concavity persists down to a very low frequency. Many authors have argued that the observed $\sigma(\omega)$ should be interpreted in terms of a frequency dependent scattering rate τ_*^{-1} defined as

$$\sigma(\omega) = \frac{ne^2}{m^*(\omega)}\frac{1}{\tau_*^{-1}(\omega) - i\omega} \tag{19}$$

In the dc limit $\tau_*^{-1}(\omega)$ is supposed to be proportional to T, with constant of proportionality determined from the requirement that $\frac{ne^2}{m^*}$ reproduce the London penetration depth. In the $YBa_2Cu_3O_7$ samples of [18] this implies $\tau_*^{-1} \approx 2T$. In the inset to Fig. 1 we compare the data to the naive ansatz a frequency independent scattering rate $\hbar/\tau = 2T$. As can be this leads to seen in the inset, this leads to a conductivity which has too little upward concavity at low frequencies, in contrast to Eq (13) which fits well over the entire frequency range. The observed upward concavity implies that the intrinsic low-frequency scattering rate is much smaller at $T = 200\ K$ than $\tau_*^{-1} = 2T$ obtained from the naive analysis. The discussion of σ_2/σ_2 to be presented below will show that the intrinsic rate varies as T^2, not as T. Both of these facts follow directly from our model but seem otherwise difficult to understand.

We now turn to the high frequency behavior. The deviation between data and naive Drude model visible in Fig. 1 has been previously been attributed to an anomalous frequency dependent scattering although a generally accepted microscopic derivation has not been found. One difficulty is that many mechanisms for producing a T-linear resistivity involve scattering off quasistatic fluctuations; such scattering leads to a too weak frequency dependence of the scattering rate and therefore to a too rapid decrease of $\sigma_1(\omega)$. For example, in the gauge theory approach one finds $\sigma_1(\omega) \sim \frac{1}{T+\omega^\alpha}$ with $\alpha = 4/3$ or $3/2$ depending on whether spinons or holons dominate the transport [19]. Another difficulty is that in most models the ω and T dependences add, leading to a T dependence of the high frequency σ which is inconsistent with the data. By contrast, in the present approach the frequency dependence is essentially a phase space effect and there is therefore only little T dependence at large ω. An alternative model which gives the correct high ω behavior is the Luttinger model of Anderson [20].

To further characterize the conductivity we consider the conductivity phase angle, $\frac{\sigma_2(\omega)}{\sigma_1(\omega)}$. In Fig. 2 we show data for this quantity for $YBa_2Cu_3O_7$ at $T = 95\ K$ that have been provided to us by Basov *et al* and data at $T = 250\ K$ that we extracted from Ref. [21].

Before proceeding with a more detailed analysis it should be noted that Basov *at al* conductivity data were obtained on untwinned crystals with the light polarized in the direction perpendicular to the chains and so this conductivity does not include contributions from the chains in contrast to the data of Ref [18,21] obtained on twinned samples. This is why the absolute magnitude of σ_1 at $\omega \lesssim 500\ cm^{-1}$ obtained by Basov *et al* are smaller in magnitude than those reported by Orenstein *et al* by a factor of 2 at $T \approx 100\ K$. This makes a detailed comparison difficult. Qualitatively, however, we see that the phase angle tends to a value of the order of unity at high frequencies, and that the crossover from the high frequency limit occurs at a relatively low frequency. The fact that phase angle tends to a constant implies that the real and imaginary parts of the conductivity vary as $\omega^{-\alpha}$; that the constant is near unity imples that $\alpha \approx 1/2$ (in general if $\sigma \propto \omega^{-\alpha}$, $\sigma_2/\sigma_1 \to \tan(\alpha\pi/2)$) consistent with our form Eq (13). We also note that high frequency limit $\sigma \propto 1/\sqrt{\omega}$ is in a reasonable agreement with the empirical observation [23] that for many high-T_c materials the high frequency conductivity obeys a scaling $\sigma_1(\omega) \sim \omega^{-\alpha}$ with $\alpha \approx 0.6$. We further note that the widespread practice [23] of plotting $1/\tau^* \equiv \frac{\omega\sigma_1(\omega)}{\sigma_2(\omega)}$ is not very informative in such cases, the constant high frequency limit of the ratio guarantees an apparently linear "scattering rate". Despite the uncertainties we have fit the observed frequency dependence of the phase angle to our theoretically expected form $\tan\left[\frac{1}{2}\tan^{-1}(\omega\tau)\right]$; the results are shown in Fig. 2 along with the data. Surprisingly, $1/\tau_{FL}$ used in these fits agrees well in magnitude with that determined from the dc conductivity or the data of [18]. We emphasize that one sees directly from the data in Fig. 2 that there is an intrinsic frequency scale in the problem which varies more nearly as T^2 than as T at low temperatures. This frequency scale occurs naturally in our model.

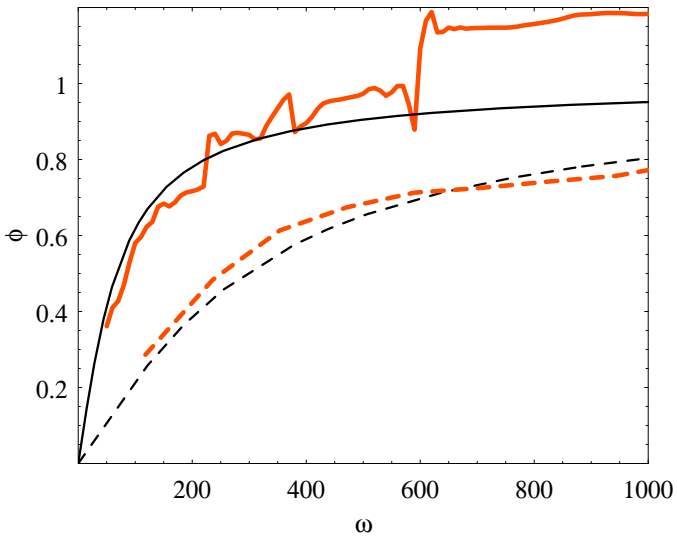

Fig. 2 Optical conductivity phase angle $\phi = \sigma_2/\sigma_1$ plotted versus frequency (cm^{-1}): data at 95 K from [22] and at 250 K from [21] (thick dashed curve) and fit to Eq (13) with $\tau_{FL}^{-1} = 6\ meV$, (thin curve) and $\tau_{FL}^{-1} = 28\ meV$ (thin dashed curve).

We now turn to the weak-field Hall conductance. We have

$$\cot(\Theta_H) = \frac{1}{\omega_c \tau_{FL}} \left[1 - i\omega\tau_{FL}\right] \tag{20}$$

Thus the model yields the $\cot(\Theta_H) \sim T^2$ law found experimentally. More interestingly, it implies that over a wide frequency range $Re\cot(\Theta_H) \sim const$ and $Im\cot(\Theta_H) \sim -\omega/\omega_c$. Precisely this behavior has been observed experimentally (see Fig. 4 of Ref. [24]). From

these data we may infer that at $T = 100\ K$, $B = 8\ T$, $\omega_c \approx 1.25\ cm^{-1}$ and $\tau_{FL}^{-1} \approx 6\ meV$, consistent with τ_{FL}^{-1} inferred from the σ_{xx} conductivity. Thus at $T = 100\ K$ the scattering rate determined from the ac Hall effect is numerically the same as that determined from the zero field ac conductivity. Ac Hall data at other temperatures are not available but the observed T^2 dependence of the dc Hall angle suggests to us that all temperatures the "Hall scattering rate" is identical to our τ_{FL}^{-1}, and is not an independent quantity. Extension of the optical Hall angle data to higher temperature and frequencies would be of great interest: the present model predicts the frequency dependence should persist to high frequencies until the ω^2 term in τ_{FL}^{-1} becomes important; a hint of this behavior may be discerned in the data of Ref. [24] although the measured $\tau^{-1}(\omega)$ is constant within error bars. Further, the only temperature dependence should be a T^2 variation of $Re\cot(\Theta_H)$.

An interesting question concerns the thermopower, which is also anomalous in high-T_c materials. The anomalies in the thermopower have been argued to scale in the same way as the cotangent of the Hall angle [25] However, we do not have a reliable calculation of thermopower in our model.

We turn now to the magnetoresistance, where a troubling discrepancy exists between model and data. Assuming the magnetic field does not affect the scattering mechanism we find

$$\frac{\delta\rho_{xx}}{\rho_{xx}} = (2.5\Gamma_0\tau_{FL} + 1)\tan^2(\Theta_H) \tag{21}$$

Thus in this model the weak field magnetoresistance is very large compared to the square of the tangent of the Hall angle and has an additional temperature dependence. These results strongly contradict available data [26] which suggest that $\frac{\delta\rho}{\rho\tan^2(\theta_H)}$ is about 1 at all temperatures in optimally doped and underdoped $YBa_2Cu_3O_{7-\delta}$ and optimally doped and underdoped $Tl_2Ba_2CuO_{6+\delta}$. The observed ratio $\frac{\delta\rho}{\rho\tan^2(\theta_H)}$ is much larger in $LaSrCuO_4$ but because this is a very resistive material and we do not know how to interpret these data within our model. We regard the $YBa_2Cu_3O_{7-\delta}$ and $Tl_2Ba_2CuO_{6+\delta}$ as more representative of the intrinsic behavior of high T_c materials.

There are two possible resolutions of this discrepancy. Either the model is simply inapplicable, which seems unlikely in the view of the photoemission results and the successes of the optics, or the anomalous scattering rate is itself field dependent in such a way as to cancel the $\Gamma_0\tau$ term in Eq. (15). Because it is likely that the anomalous scattering rate is related to pairing fluctuations a strong B dependence of the scattering rate is possible.

We briefly discuss impurity dependence. We expect $\tau_{FL}^{-1} = \tau_{imp}^{-1} + T^2/T_0$ with the impurity scattering rate τ_{imp}^{-1} linearly dependent on the defect density n_d. Eq. (13) for σ_{xx} then predicts strong violations of Matthiesson's rule: the $T = 0$ residual resistivity is predicted to go as the square root of the defect density and the difference $\rho(T, n_{d1}) - \rho(T, n_{d2})$ in resistivity between two otherwise identical samples with different defect density should be temperature dependent, decreasing as T is increased. Neither of these predictions is consistent with available data [27]. We note, however, that the data mostly involve doping on the Cu site. Such doping is known to drastically change the local environment (e.g. by inducing magnetic moments on nearby Cu sites [28]). Further, we note that in all available data, doping increases the slope $d\rho/dT$, presumably because the doping changes an effective carrier number. These effects cannot be modelled by simply a $1/\tau_{imp}$ to a theory; therefore we do not regard the inconsistency between the predicted and observed doping dependence of ρ as a definitive disproof of the model we have proposed.

IV. MICROSCOPIC ORIGIN

In this section we present a qualitative discussion of a possible origin for the unusual lifetime we proposed. The angular dependence is reminiscent of that of the $d_{x^2-y^2}$ superconducting gap; we therefore propose that the lifetime is caused by interaction of electrons with nearly singular $d_{x^2-y^2}$ pairing fluctuations. Similar ideas have been proposed by Chubukov [29]. As an example of an interaction which yields the desired behavior we consider

$$\Gamma(p, p', q) = \Gamma \sin 2\theta_p \sin 2\theta_{p'} D(\omega, q) \tag{22}$$

with the pair fluctuation propagator $D(\omega, q)$ given by

$$D(\omega, q) = \frac{\phi[\frac{\omega^2}{u^2(q^2+\xi^{-2})}]}{q^2 + \xi^{-2}} \tag{23}$$

Here Γ is an energy scale, $sin(2\theta_p)$ is the usual d-wave form factor and ϕ is a scaling function. the form of ϕ is not important; it is however necessary to assume $\int dx\phi''(x)$ is convergent and indeed of order unity. Note that we have assumed $\omega \sim uq$ scaling. This is a nontrivial (but widely made) assumption for which we do not have a theoretical justification.

We may construct a one-loop self-energy from the interaction Γ in the usual way. We have (here p and q represent both momentum and frequency)

$$\Sigma(p) = \int (dq)\Gamma(p - q/2, p - q/2, q)G(p + q) \tag{24}$$

We are interested in momenta near the zone diagonal where the self energy is small. We assume $p_F\xi \gg 1$. We may therefore approximate $G(p+q)$ by its weak coupling form $G(p) = (\omega - v_F(|p| - p_F))^{-1}$. After integration over the magnitude of $|p+q|$ we obtain for the imaginary part Σ'' as a function of position θ on the fermi line

$$\Sigma''(\theta) = \frac{p_F\Gamma}{v_F}\int \frac{d\theta'}{2\pi}\frac{d\omega}{2\pi}\sin^2(2(\theta-\theta'))\frac{\phi''(\frac{\omega^2}{p_F^2\theta'^2+\xi^{-2}})}{p_F^2\theta'^2+\xi^{-2}} \tag{25}$$

Now ϕ'' is peaked at $\omega \sim u\sqrt{(p_F\theta)^2+\xi^{-2}}$ and vanishes as $\omega \to 0$; thus the integral is dominated by $\theta' \sim (p_F\xi)^{-1}$. for $\theta \gg (p_F\xi)^{-1}$ we find $\Sigma''(\theta) \sim \frac{u\Gamma}{v_F}\sin^2(2\theta)$ while for $\theta \ll (p_F\xi)^{-1}$ we get $\Sigma''(\theta) \sim \frac{u\Gamma}{v_F}(p_F\xi)^{-2}$. Further the $\omega \sim uq$ scaling implies $\xi \sim u/T$. Thus the interaction leads to a scattering rate which is roughly of the form $max(\Gamma_0\theta^2, T^2/T_0)$ with $\Gamma_0 \sim \frac{u}{v_F}\Gamma$ and $T_0 \sim \frac{(up_F)^2}{\Gamma_0}$ as required for the previous analysis. The empirically determined $T_0 \approx 12\ meV$ and $\Gamma_0 \approx 0.6\ eV$ implies $u \sim 0.15\ eV\mathring{A} \sim 0.1v_F$. Therefore the one-loop approximation may be justified by the usual Migdal arguments. Within the one-loop approximation the frequency dependence of Σ may be determined; it is very weak (logarithmic), justifying its neglect in the phenomenological analysis.

The crucial features of the interaction are (i) it must be rather sharply peaked about $q = 0$ so as not to mix different parts of the Fermi surface too strongly, (ii) it must be a singular function of ω, so as to produce a large, essentially T-independent scattering rate for θ away from the zone diagonal and (iii) the basic scale (set by ξ^{-1}) is T. We expect these assumptions to apply for optimally doped materials. For underdoped materials we conjecture that the system is closer to an instability, i.e. $\xi^{-1} \ll T$ implying a more singular interaction which leads among other things to a pseudogap in the density of states (see [30] for a similar calculation). For overdoped materials we expect at low T that $\xi^{-1} \gg T$; in this case the analysis leads to a scattering rate proportional to $T^2\xi^2(\theta^2+\xi^{-2})$, i.e. one which is T^2 everywhere on the Fermi surface but is very anisotropic.

Here we have also made the additional assumption that this interaction exists in the pairing channel, i.e. it is due to multiple scattering with virtual Cooper pairs. These virtual Cooper pairs will lead to a paraconductivity; we now show that this paraconductivity is negligible in comparison to the normal carrier conductivity found in the previous section. The paraconductivity σ_{para} is

$$\sigma_{para} = \int \frac{q^2d^2qd\omega}{(2\pi)^3}\frac{(\mathrm{Im}D(\omega,q))^2}{2T\sinh^2(\omega/2T)} \tag{26}$$

Evaluation and restoration of dimensional factors leads to $\sigma_{para} \approx \sigma_0(T\xi)^a$ with $\sigma_0 = \frac{e^2}{h}$ and $a = 1$ if $(T\xi) \gg 1$ and $a = 2$ if $(T\xi) \ll 1$; because we expect $(T\xi) \sim 1$ this paraconductivity is small compared to the quasiparticle conductivity calculated previously, $\sigma \sim \frac{e^2}{h}v_Fp_F\sqrt{\frac{\tau}{\Gamma_0}} \gg \frac{e^2}{h}$.

V. CONCLUSION

We have considered a model based on "cold spots"; i.e. the idea that the quasiparticle lifetime τ is unusually short everywhere on the Fermi line except near the zone diagonals. Direct evidence for this behavior is found in photoemission experiments. Using a Boltzmann equation analysis we have shown that the ansatz $\tau(\theta,T) = \frac{1}{\Gamma_0\theta^2+T^2/T_0}$ with $\Gamma \approx 0.5\ eV$ and $T_0 \approx 12\ meV$ reproduces quantitatively the observed dc and ac, longitudinal and Hall conductivities of optimally doped materials. We regard it as particularly significant that the model reproduces the non-Drude form of the observed optical conductivity (both the upward curvature at low frequencies and the roughly $1/\sqrt{\omega}$ behavior of Reσ and Imσ at $\omega > 400\ cm^{-1}$) and the difference between longitudinal and Hall scattering rates.

There are two differences between model predictions and the data. The effects of impurity scattering are different than predicted; however a comparison is difficult because published doping studies have involved substitution on Cu site which produces many confusing changes in the material. Electron damage or light doping on sites away from the CuO_2 planes in *very clean* samples would provide a more definite test. A more troubling discrepancy is the magnetoresistance which is predicted to have a much larger magnitude and stronger temperature dependence than is observed. We do not at present have a resolution, but the other successes of the phenomenology lead us to believe one may be found. We also showed that the anomalous lifetime could arise from the exchange of virtual Cooper pair fluctuations. If this is the case, then the anomalous scattering would get weaker in an applied magnetic field, perhaps reducing magnetoresistance.

Finally, we comment on the energy scale, T_0, characterizing the "Fermi liquid" scattering rate $1/\tau_{FL} = T^2/T_0$. The data imply $T_0 \approx 12\ meV$, a surprisingly small value corresponding to strong scattering even along the diagonals. (Note that the ac Hall measurements of Ref. [24] combined with the observed T^2 Hall angle dependence directly implies the existence of such small energy scale in the material) Thus for T of order room temperature T^2/T_0 is of the order of the smallest fermion Matsubara frequency, πT, suggesting that even along the diagonals fermi liquid behavior breaks down for $T > 300\ K$. The small value of T_0 implies that even the "Fermi liquid" T^2 scattering must be due to some anomalous singular scattering mechanism, for example the virtual Cooper pair fluctuations considered in Section IV.

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